

Docket No.: F03-354-USDiv
FUJIT.044DIV



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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Hisaki KATO, et al.

Serial No.: 10/634,836

Group Art Unit: 2822

Filed: August 6, 2003

Examiner: Keisha L. Rose

For: LIGHT-EMITTING SEMICONDUCTOR DEVICE USING GALLIUM
NITRIDE COMPOUND SEMICONDUCTOR

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

**REQUEST FOR CONSIDERATION OF
INFORMATION DISCLOSURE STATEMENT**

Sir:

Applicants respectfully submit that notification of consideration of the references submitted with the Information Disclosure Statement and Form PTO-1449 filed July 6, 2005 (copy enclosed), has not yet been received. A copy of the date-stamped postcard is also enclosed. Applicants respectfully request that these references be considered by the Examiner and formally made of record in this application, and that notification of such consideration be issued.

Respectfully submitted,

Scott M. Tulino, Esq.
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Date: July 19, 2005
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Attorney's Post Card Filing Receipt Serial No. 516105
Serial Number: 101634836 Papers Filed On: 5/19/05

Attorney's Docket Number: FW 3 3547(51) Patent Trademark

Applicant's Name: Hisatomi KATO et al., Application Filing Date: 5/16/05
Papers Filed Herewith:

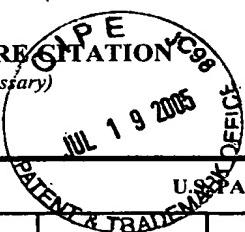
- Amendment Request for Extension of Time CPA Request
 Notice of Appeal Appeal Brief (in triplicate) Reply Brief
 IDS JUL 06 2005 1449 Form w/ 2 Documents Priority Document(s)
 Assignment Recordation Cover Sheet Formal Drawings
 Drawing Corrections Issue Fee Transmittal Missing Parts

Other Japanese Office Action, dtd 5/24/05

Fees Filed Herewith: \$ Check Charge Deposit Account: _____

Hand Delivered

INFORMATION DISCLOSURE STATION
(Use several sheets if necessary)



Docket Number (Optional)
F03-354-USDiv

Application Number
10/634,836

Applicant(s)
Hisaki KATO, et al.

Filing Date
August 6, 2003

Group Art Unit
2822

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

U.S. PATENT APPLICATION PUBLICATIONS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
	H7-7182	01/10/99	Japan				Abs

OTHER DOCUMENTS *(Including Author, Title, Date, Pertinent Pages, Etc.)*

		Japanese Office Action, dated May 24, 2005, with partial English translation
		NAKAMURA, et al., "Ridge-geometry InGaN multi-quantum-well-structure laser diodes", APPLIED PHYSICS LETTERS, September 2, 1996, Vol. 69, No. 10, pp. 1477-1479

EXAMINER	DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.